

09/936818

ISSUE CLASSIFICATION	
Subseries	Class

FILED UNDER 35 U.S.C. 371

U.S. UTILITY Patent Application

Q.I.P.E.

PATENT DATE

APPLICATION NO. 09/936818	CONT/PRIOR D F	CLASS 257	SUBCLASS 8	ART UND 2811	EXAMINER S
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Method of crystal growth, method of forming fine semiconductor structure, semiconductor device, and system

PTO-2040
12/99

ISSUING CLASSIFICATION

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TERMINAL DISCLAIMER		DRAWINGS		CLAIMS ALLOWED	
		Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims _____
The terminal disclaimer filed on [REDACTED] (2015) has been disclaimed.				Final Claim for © Gu	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____ <hr/> <hr/>		(Assistant Examiner) _____ (Date) _____		NOTICE OF ALLOWANCE	
<input checked="" type="checkbox"/> The terminal _____ months of this patent have been disclaimed. <hr/> <hr/>		(Primary Examiner) _____ (Date) _____		ISSUE FEE	
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